

Taiwan Semiconductor

4A, 200V - 600V Ultrafast Glass Passivated Rectifiers

FEATURES

- Ideally suited for use in very high frequency switching power supplies, inverters and as free wheeling diodes
- Ultrafast recovery time for high efficiency
- Excellent high temperature switching
- Glass passivated junction
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
- AEC-Q101 qualified

MECHANICAL DATA



DO-201AD

Molding compound, UL flammability classification rating 94V-0 Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 2 whisker test **Weight:** 1.2 g (approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERSTICS (T _A =25°C unless otherwise noted)					
PARAMETER	SYMBOL	MUR420	MUR440	MUR460	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	V
Maximum RMS voltage	V _{RMS}	140	280	420	V
Maximum DC blocking voltage	V _{DC}	200	400	600	V
Maximum average forward rectified current	I _{F(AV)}	4			А
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	125			А
Maximum instantaneous forward voltage (Note 1) @ 4 A	V _F	0.89	1.28		V
Maximum reverse current @ rated VR T _J =25 °C T _J =125 °C	I _R	5 150	10 250		μA
Maximum reverse recovery time (Note 2)	t _{rr}	25	50		ns
Typical junction capacitance (Note 3)	CJ	65			pF
Typical thermal resistance	R _{θJA}	28			°C/W
Operating junction temperature range	TJ	- 55 to +175			°C
Storage temperature range	T _{STG}	- 55 to +175			°C

Note 1: Pulse Test with PW=300µs, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: I_F =0.5A, I_R =1.0A, I_{RR} =0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.



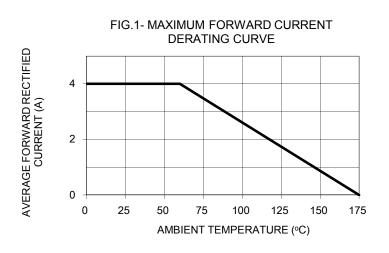
ORDER INFORMATION (EXAMPLE)

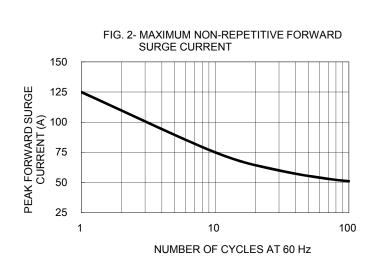
MUR460 A0G

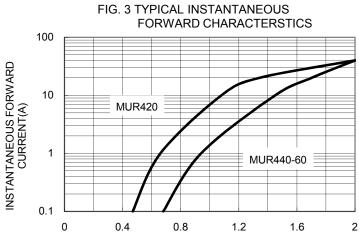
- Green compound code
- Packing code
- Part no.

RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)

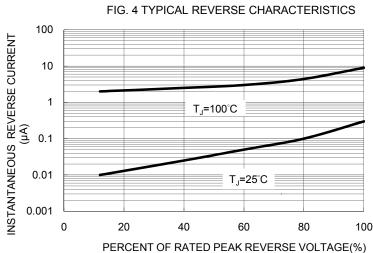






INSTANTANEOUS FORWARD VOLTAGE (V)

EOUS





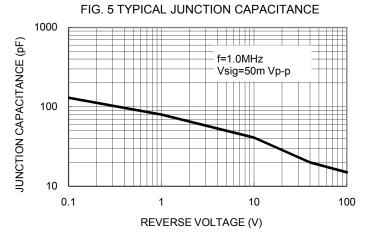
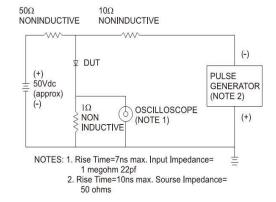
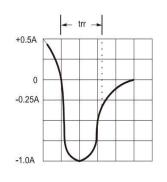
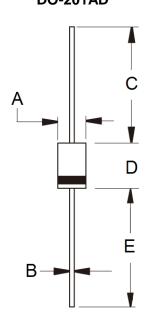


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM





PACKAGE OUTLINE DIMENSIONS DO-201AD



Unit (mm) Unit (inch) DIM. Min Min Max Max А 5.00 5.60 0.197 0.220 0.048 0.052 В 1.20 1.30 С 25.40 1.000 _ -D 8.50 9.50 0.335 0.375 Е 25.40 1.000 _

MARKING DIAGRAM



P/N =

G =

F =

- Specific Device Code Green Compound
- Date Code
- YWW = Factory Code

Document Number: DS_D1405023



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